Holstein polarons in a strong electric eld: delocalized and stretched states

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The coherent dynamics of a Holstein polaron in strong electric elds is considered under di erent regimes. Using analytical and numerical analysis, we show that even for small hopping constant and weak electron-phonon interaction, the original discrete W annier-Stark (W S) ladder electronic states are each replaced by a sem i-continuous band if a resonance condition is satis ed between the phonon frequency and the ladder spacing. In this regime, the original localized WS states can become delocalized, yielding both 'tunneling' and 'stretched' polarons. The transport properties of such a system would exhibit a modulation of the phonon replicas in typical tunneling experiments. The modulation will react the complex spectra with nearly-fractal structure of the sem i-continuous band. In the o -resonance regime, the WS ladder is strongly deformed, although the states are still localized to a degree which depends on the detuning: Both the spacing between the levels in the deform ed ladder and the localization length of the resulting eigenfunctions can be adjusted by the applied electric eld. W e also discuss the regim e beyond sm all hopping constant and weak coupling, and nd an interesting mapping to that lim it via the Lang-F irsov transform ation, which allows one to extend the region of validity of the analysis.

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I. IN TRODUCTION

Quantum electronic transport properties in sem iconductor superlattices in high electric elds have been the subject of much interest in recent years. Experimental studies have reported interesting phenom ena, such as B loch oscillations and W annier-Stark (W S) ladders.¹ M oreover, a num ber of theoretical predictions have been m ade, including negative di erential conductivity, dynam ical localization, 3 and fractional W S ladders under DC and AC $elds_{r}^{4}$ to name a few.

One important issue for the dynam ical behavior of a real system is the e ect of electron-phonon interactions, and extensive research in this eld has been reported. For example, Ghosh et al. and Dekorsy et al. studied coupled B loch-phonon oscillations.⁵ T he phonon-assisted hopping of an electron on a W S ladder was studied in [6]. A brilliant variational treatm ent of inelastic quantum transport was given in [7], and anom alies in transport properties under a resonance condition were studied in [8]. Govorov et al. studied the optical absorption associated with the resonance of a W S ladder and the optical phonon frequency in a system .9,10 A similar and fascinating system of electron-phonon resonance in magnetic elds has also been studied extensively.

Much of the work in this area considers incoherent scattering of electrons by phonons, which is the relevant picture in systems at high temperature. In this paper, how ever, we report a study of the e ects of coherent coupling of an electron to the phonons of the system, likely to be the relevant description at low temperatures. We concentrate on how the phonon coupling a ects electron transport in high electric eld, in a situation typically achieved in sem iconductor superlattices, for instance, but also important for electrons in polymer chains,¹² and

even perhaps reachable in a stack of self-assem bled quantum dots.13

Based on a Holstein model,¹⁴ typically used to describe the small polaron in molecular systems, we analyze the spectrum of the system and study its transport properties. W e use here a non-perturbative description, which allows one to elucidate the e ects of resonant and nonresonant phonon elds on the otherwise localized electrons residing in a W S ladder, for both weak and strong electron-phonon coupling. We nd that for sm all hopping and coupling constant, an interesting regime results when two characteristic energy scales in the system coincide: the one corresponding to the energy spacing between the W S levels, and the other corresponding to the frequency of the phonons. In this resonant case, the problem is one of strong mixing between degenerate states with rather di erent properties. The result is a com plex sem i-continuous band structure replacing each of the original WS ladder 'rungs', where som e of the electron states become delocalized, despite the strong electric eld present. In this case, the phonons interacting with the electron provide delocalization, unlike the usual situation. M oreover, and in contrast to these extended states, 'stretched polarons' are highly degenerate and exhibit strongly localized electronic components, while the phonon component is in fact extended throughout the structure. W hen the system is away from the resonance condition, a deform ed W S ladder will appear, with very interesting substructure. The electronic wave functions in this regime are all localized, but with a localization length that depends linearly on the degree of detuning.

In all phonon frequency regimes, the rich dynamical behavior of the system is due to (or re ected in) the near fractalstructure of the spectrum . This, as we will discuss, has a direct connection to the Cayley tree structure of

the relevant H ilbert space. This structure is of course contained in the Ham iltonian and re ected also in the structure of the eigenvectors.

We also extend our studies beyond the weak coupling and sm all hopping constant regime, via a Lang-Firsov transform ation. This results in an interesting mapping of the problem from the strong coupling to the weak limit, and allow some to extend the results for a wider parameter range. A rst report of the resonant case in the weak coupling regime has been published.¹⁵ Here, we give a detailed theory of such states, including both resonant and non-resonant cases, and present the strong coupling interaction regime.

In what remains of the paper, we give in section II a description of the model used and the relevant H ilbert space in the problem. Section III contains a complete analysis of the resulting spectrum for small hopping constant and weak phonon coupling. The extension beyond that regime is given in section IV. A nal discussion is presented in section V.

II. DESCRIPTION OF THE MODEL

W e consider the Holstein model,¹⁴ which describes an electron in a one-dimensional tight-binding lattice, interacting locally with dispersionless optical phonons. Moreover, the system is subjected to a strong static electric eld. The Ham iltonian is then given by

where t is the electron hopping constant, ! the phonon frequency (or energy, with ~ = 1), the electron-phonon coupling constant, " $_j$ = edE j j the site energy, E the electric eld, and d is the lattice constant. It is known that a series of localized W S states will form in a strong eld (= edE t), in the absence of interactions between electron and phonons. W ithin tight-binding theory, the eigenvalues and eigenfunctions of these W S states are, respectively " $_j$ = edE j, and

$$j_{ji} = \int_{i}^{P} J_{ij} (2t - edE) ji;$$
 (2)

where J_1 is the 1-th order B essel function . The W S states are localized states with characteristic length 2t=eE .

It is helpful to introduce creation and annihilation operators for W S states as

$$d_{j} = \prod_{i=1}^{P} J_{i,j} (2t = edE) c_{i}:$$
(3)

It is easy to show that this transform ation is canonical, $fd_i^+; d_jg = i_j$, and that the H am iltonian can be written in term s of $d_j; d_i^+$ as

$$H_{0} = \int_{j} d_{j}^{\dagger} d_{j} + [a_{j}^{\dagger} a_{j}]$$

+
$$J_{j i} J_{j i^{0}} (a_{j} + a_{j}^{+}) d_{i}^{+} d_{i^{0}}$$
: (4)

In the case of strong electric eld (or sm all hopping constant, 2t= 1) in which we concentrate in this section, the H am iltonian can be simpli ed as

$$H = \begin{array}{cccc} X & X & X & X \\ j & d_{j}^{+} d_{j} + ! & a_{j}^{+} a_{j} + & d_{j}^{+} d_{j} (a_{j}^{+} + a_{j}) \\ X^{j} & j & j \\ (a_{j} + a_{j}^{+} & a_{j+1}^{+} & a_{j+1}) (d_{j}^{+} d_{j+1} + d_{j+1}^{+} d_{j}); \\ j & (5) \end{array}$$

where the e ective coupling constant is now

$$=$$
 t= : (6)

From (5), one can see phonon-assisted hopping between the W S states quite clearly, so that in fact the phonons introduce delocalization of the W S electrons. The H am iltonian (5) is similar to that in [9], but there are some differences. In the current model, when an electron jumps from one site to the next, it can not only emit (or absorb) a phonon on (from) its site, but also onto (from) the nearby site. This more natural description also produces a large di erence on the relevant H ilbert spaces. The dimension of the relevant H ilbert spaces. The dimension of the relevant H ilbert space in our case is 2^n 1, where n is the num ber of local sites in the chain, while the size is n for the model in [9]. A swe will see, the resulting energy spectrum and other physical quantities show quite a rich behavior.

Let us consider the process of an electron jumping between sites while creating or annihilating phonons in its neighborhood. For example, for a chain of three sites, n = 3, the hopping of the electron from the rst site will connect the states jl;000i, jl;010i, jl;100i, jl;011i, jl;101i, jl;020i, and jl;110i. Here a vector is expressed as jj;::m₀;m₁;::i, where j is the electron position, and m_k refers to the number of phonons on site k. It is interesting to see that the connectivity of this portion of H ilbert space has the structure of a Cayley tree, or a B ethe lattice.¹⁶ Under the condition of resonance, i.e.,

= !, all the states above for n = 3 have the same energy. The o -diagonal matrix elements therefore break the degeneracy and allow level mixing, and one can expect that some kind of band may form in the limit of large n. A swew ill see later on, and in contrast to the resonant case, the spectrum in o -resonance is still composed of ladders although with a complex structure.¹⁷

In the basis we list above, the H am iltonian for n = 3 takes the form

$$H = \begin{bmatrix} 0 & & & & 0 & & 0 & & p \frac{0}{2} & & 0 & 1 \\ 0 & & & & & 0 & & p \frac{0}{2} & & 0 & c \\ 0 & & 2 + ! & 0 & & & 0 & & c \\ 0 & & 0 & & 3 + 2! & 0 & & 0 & c \\ 0 & & p \frac{0}{2} & & 0 & & 3 + 2! & 0 & & 0 \\ 0 & & 0 & & 0 & & 0 & 3 + 2! & 0 & A \\ 0 & 0 & & 0 & 0 & & 0 & 3 + 2! & 0 & A \end{bmatrix}$$
(7)

A direct consequence of the Cayley tree connectivity of the near degenerate basis is that the Ham iltonian (7) is constructed by diagonal block matrices for ever larger n (of sizes 1, 2, 4, ..., 2^{n-1}), and m ixed by o -diagonalm atrix elements proportional to . One can see that in the resonant case, all diagonal elements are given by , corresponding to the degenerate manifold. Notice also that the o -diagonal elements are given by p / except for a few sporadic elements which appear as 2 , associated with higher number of phonons in a site, such as the state 3;020i in this case. This nearly self-sim ilar structure appears for all values of n. W e expect then that there would be little change in the physical properties in the large n lim it if we replace 2 in those . This will be con med few o -diagonal spots with by our num erical calculation, as we will see below. A fter the substitution, the new sym m etrized H am iltonian H $_{\rm sym}$ takes a full self-sim ilar form , and allows one to exactly solve analytically the eigenvalue problem, and better understand the physics of the system . Much of the behavior of H $_{\rm sym}\,$ remains in the actual system described by H .

III. SMALL HOPPING AND WEAK COUPLING REGIME

Let us consider the eigenvalue problem for the Ham iltonian H $_{sym}$, de ned as that in (7), except that the elem ents 2 are replaced by . By using the block decomposition formula

$$det \begin{array}{c} A & B \\ C & D \end{array} = det(D) det(A & B D^{-1} C); \quad (8)$$

we $\;$ nd that the eigenvalues of the H am iltonian $\rm H_{sym}\;$ are determ ined by the equation

$$\mathbf{n}_{0}^{N=2} \mathbf{n}_{1}^{N=4} \mathbf{n}_{2}^{N=8} \dots \mathbf{n}_{n-1}^{1} = 0; \qquad (9)$$

where N = 2^n , " $_0$ = " t_k, " is the energy eigenvalue, t_k is de ned by

$$t_k = (n \quad k) (! \quad) \quad !; \quad (10)$$

and

$$\mathbf{w}_{k+1} = \mathbf{w}_{k} \frac{2^{2}}{\mathbf{w}_{k}}$$
: (11)

Then, ${\sf "}_k$ can be written as a continuous fraction in k steps

$$\mathbf{x}_{k+1} = \mathbf{w}_{k} = \frac{2^{2}}{\mathbf{w}_{k-1}} = \frac{2^{2}}{\mathbf{w}_{k-2}} :$$
 (12)

A. Resonant regime (= !)

In this case, $t_k = 0$ (after a constant energy shift of ! is m ade), we obtain the eigenvalues of H _{sym} as

$$_{k;j} = 2^{p} \overline{2} \cos \frac{j}{k+1}$$
; (13)

where k = 1;2;:::;n, and j = 1;:::;k. The asymptotic bandwidth of the spectrum is therefore given by 4^{-2} . Notice that this behavior is similar to that of a system in magnetic elds. In that case, the electron-phonon interaction breaks the degeneracy (under the condition of magnetic resonance) and leads to a \resonance splitting." In that case, the splitting is / $^{2=3}$ for a three dimensional system, and / $^{1=2}$ for a two dimensional system, where is the Frohlich electron-phonon coupling constant.¹¹

Let us consider the question of eigenvalue degeneracy by solving $\mathbf{u}_0^{N=2} \mathbf{u}_1^{N=4} \mathbf{u}_2^{N=8} \mathbf{u}_3^{N=16} = 0$, which will provide us with a good estimate in the large N limit. A fler some algebra, one obtains for the eigenvalue equation,

$$\mathbf{n}^{5N=16} (\mathbf{n}^2 \quad 2^2)^{N=8} (\mathbf{n}^2 \quad 4^2)^{N=16}$$

$$(\mathbf{n}^4 \quad 6^{\mathbf{n}^2 \quad 2} + 4^{-4})^{N=16} = 0:$$
(14)

W epthen have eigenvalues " = 0, $\frac{P}{2}$, 2, and

3 5, with respective degeneracies of 5N =16, N =8, N =16, and N =16. Higher order polynom ials would slightly in prove the degeneracy estimate for successively higher eigenvalues.

O ur num erical results for the eigenvalues of H $_{\rm sym}$, Fig. 1, and H, Fig. 2, exhibit very similar characteristics, as expected. The di erent panels in these gures show spectra for n = 8, 9, and 11. One can see that the main structure of the spectra changes little with increasing n, although ner structure appears for higher n, lling to



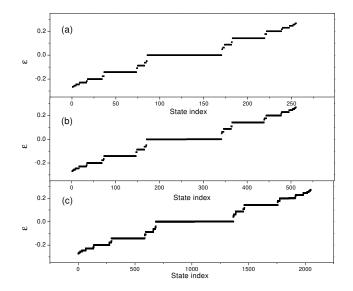


FIG.1: Energy spectra for fully self-sim ilar H _{sym} for system s with di erent lattice size, (a) n = 8, (b) n = 9, and (c) n = 11. Notice the clear fractal structure of spectra, as anticipated from the structure of H _{sym}. Increasing n produces ner scale structure in the gaps. Here $= \frac{1}{2} = 1$, and = 0.1, so that the asymptotic bandwidth is $4^{-2} = 0.5657$.

som e extent the gaps of the previous structure. O ur analytical results m atch exactly those of F ig. 1. The selfsim ilar structure of the spectrum is the manifestation of such symmetry in H_{sym} . One can see that the original highly degenerate manifold is broadened into a sem icontinuous band by the o -diagonal mixing elements of H_{sym} . Notice however that large residual degeneracies remain at the center of the band, and other symmetrical values, as described above by Eq. (14).

The structure of the full H am iltonian H is shown in Fig. 2, which still maintains a nearly self-sim ilar structure, despite the sporadic $\overline{2}$ asymmetrical terms. Notice however that the degeneracy at " = 0 and other plateau values' is not exact here, but only seen as a slight break (or slope) of each plateau.

Figure 3 com pares the results for the bandwidth of H and H_{svm} from both analytical and num erical results. Notice that 4 2 is the asymptotic (large n) analytical result from Eq. (13), for H $_{\rm sym}$. W e see in Fig. 3 that the num erical results for the bandwidth of H $_{\rm sym}\,$ converge quickly to the analytical prediction. Sim ilarly, the num erically obtained bandwidth of H is only slightly larger than the bandwidth of H $_{\rm sym}$, and clearly has also a nite asymptotic value. This is an interesting feature of H, that although one has large H ilbert space dim ension 1 (= 2047 for n=11, for example), one Ν $1 = 2^{n}$ obtains a nite bandwidth. This is of course also associated with the fact that there are large degeneracies in the energy spectra, which increase with N (see Eq. 14).

To get better understanding of the physics, we show characteristic electron probabilities, as well as phonon spatial distributions, for di erent eigenstates in Fig. 4

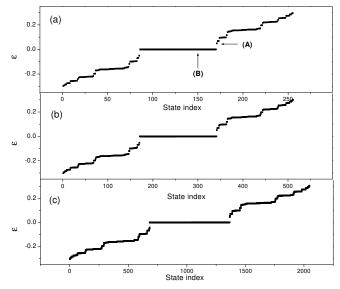


FIG.2: Energy spectra for H of system s with di erent lattice size, (a) n = 8, (b) n = 9, and (c) n = 11. Notice the approximate fractal structure of the spectra. Increasing n gives similar structure. Here = ! = 1, = 0:1, and the bandwidth slightly increases from one panel to the next. A and B labels in panel (a) indicate states described in Fig. 4 and 5.

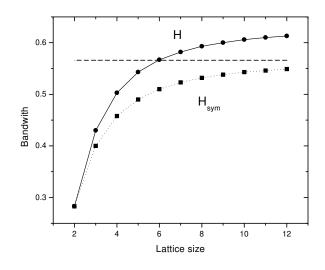


FIG.3: Bandwidth results for $\,=\,$ 0.1 and dimension values of n. The asymptotic bandwidth for H $_{\text{sym}}$ is 4 $\frac{1}{2}$ = 0.5657, shown as dashed line. We see that bandwidth for H is W & 6 .

and 5. The electronic probability function is given by

P (j) = h
$$jd_{j}^{+}d_{j}j$$
 $i = \int_{fm g}^{P} f_{j;fm g} \hat{f};$ (15)

where the coe cients in the last expressions are obtained from the diagonalization of H , so that the eigenvectors

are given by

$$j \quad i = \sum_{j; fm g}^{P} C_{j; fm g} \quad jj; fm gi; \quad (16)$$

for each -eigenstate. Similarly, the corresponding phonon spatial distribution is given by

N (j) = h
$$ja_{j}^{+}a_{j}j$$
 $i = \int_{l;fm g} jC_{l;fm g} jm_{j};$ (17)

for each eigenstate. These two spatial distribution functions give us an idea of how the two di erent components of each state are related to one another. These functions are a projection of the rather subtle coherent interactions (or mixtures) between the electron and phonon subsystem s. O ne can see in F ig. 4a that for the non-degenerate state A in Fig. 2a, the electron is extended throughout the n = 8 lattice. At the same time, the phonon am plitude is also extended along the lattice, and one can picture the phonon 'cloud' as 'surrounding' the electron all along in Fig. 4b, e ectively describing a tunneling polaron'. In contrast, the degenerate state B at " = 0in Fig. 2a, has its electron component highly localized at the right end of the lattice, Fig. 5a, while the phonon cloud is away, Fig. 5b, and nearly detached' from the electron. One can describe this as a 'stretched polaron' (a precursor of the polaron dissociation predicted at high elds in polym er system s^{2}).

A lthough by de nition the electronic distribution function P is norm alized to unity, the phonon function N is not necessarily so, since the electron can create and absorb phonons as it propagates up and down the lattice. This di erence in phonon content for each state can be seen by comparing Fig. 4b, and 5b, as the total phonon num ber is clearly larger in the latter (stretched polaron) case. To study this feature throughout the spectrum, we show in Fig. 6 the total average phonon number of all states in the chain n = 8. One can see clearly that states at the center of the band (" 0) have m any m ore phonons (7 = n 1) than the rest. A n estim ate for the average num ber of phonons for di erent states can be obtained by the following argument. The average phonon $_{i}$ P (i)m $_{i}$. For an extended num ber is given by hN i = state, P ' 1=n, for a chain of n sites. A state with an electron at site i can be obtained by the electron hopping 1 steps from the rst site, while em itting m i i 1 phonons, in the process. For extended states, this yields hNi′ ,(i 1)=n = (n 1)=2, which matches well the num erical results in Fig. 6, where the most extended states have hN i ' 3.5 (such as the state labelled A). In contrast, an electron localized at site n, as B in Fig. 6, has em itted n 1 phonons in the process, just as one

nds in the exact calculation.

1. Transport through structure

W e should emphasize that the properties illustrated in Fig. 4 and 5 are quite generic: states in one of the highly (nearly) degenerate levels show di erent degrees

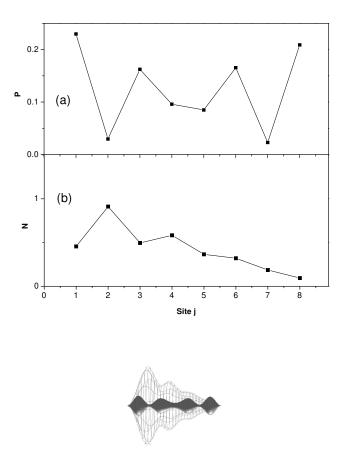


FIG. 4: (a) Electron probability P (j) for each site j, and (b) spatial distribution of phonons N (j) for state labelled A in Fig. 2a. Large electron amplitude and phonon number throughout describe an extended, delocalized polaron, jointly illustrated in the composite gure at bottom.

of electron localization and an abundance of phonons, in a stretched polaron con guration. In contrast, states with non-degenerate companions are delocalized polarons throughout the chain with low phonon content. Even though is the presence of phonons which delocalizes the electron (in the sense of the original W S ladder), we obtain that the localized electrons are accompanied by m any phonons, rem iniscent of the self-localized polarons when the coupling is strong.

The rather complicated behavior of the states would of course be relected in various properties of the system. Let us focus here on what one could measure if electrons where injected from one end of the chain and were collected out of the other end. This is motivated by the ability to carry out just such experiments under strong electric elds in semiconductor superlattices, as well as in other systems. The transport properties provide information about the density of states in the structure and the spatial charge distribution of the di erent states (for optical response, see [15]). The contribution of various

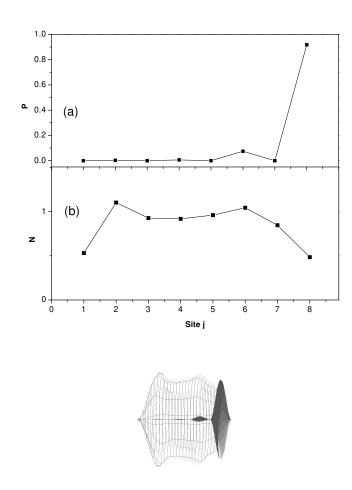


FIG.5: (a) Electron probability P (j) for each site j, and (b) spatial distribution of phonons N (j) for state labelled B in Fig. 2a. Electron is localized at right end of the chain, while phonons lie throughout, yielding a stretched polaron, illustrated at bottom gure.

eigenstates to the charge transport can be described by the quantity

$$D = P (1)P (n);$$
 (18)

since the tunneling am plitude is proportional to the density of states in the leads and the wavefunction am plitudes at both ends of the structure (the site j = 1and j = n).¹⁸ In fact, the tunneling probability can be calculated from the S-m atrix form alism as $JT \hat{j}$, where $T = h''_f; R; \tilde{j}'_i; Li$. Here R and L refer to the right and left leads. In the wide band lim it,

$$I / dt_{1} dt_{2} e^{i(f_{f} t_{2} f_{1})} m j G^{R} (t_{2} t_{1}) j i$$

$$X = m j i h j i (f_{1} f_{1});$$
(19)

where describes the electron interaction with contacts, and G^{R} is the retarded G reen function connecting both ends of the structure (j = 1 and j = n). We see then

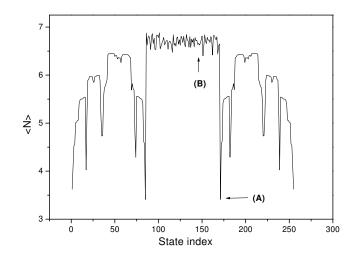
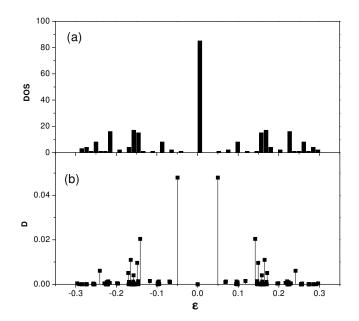


FIG. 6: Total average phonon number for each eigenstate in Fig. 2a. Higher value plateaus are associated with the more localized electronic amplitudes, such as state B. Lowest phonon counts correspond to extended electronic states, such as A.

that the quantity D = jnj in jlij / jrj is directly involved in the tunneling probability. Figure 7a shows the density of states and 7b shows the quantity D for the system with n = 8. We can see that all the states at the center of the band contribute zero to the transport am – plitude through the chain, and this behavior is exhibited by all the high peaks in the DOS. This is clearly consistent with the spatially localized charge nature of the highly degenerate states. On the other hand, D shows a large values for states 'in the gaps', con im ing in fact that the non-degenerate states in the spectrum have an extended nature. The variations shown in D would then be related in strong am plitude modulations within each of the phonon replicas in tunneling experiments,¹⁹ whenever the resonance regime is reached.

B. Non-resonant regime (€ !)

By studying the equivalent continuous fraction (12) for the non-resonant regime, we nd that the spectrum for this case is quite di erent from that under resonance. For the case of sm all coupling constant, i.e., =! 1, and = 1, the unperturbed spectrum is a series of ladder levels "j = (!) j (j = 1; :::; n) instead of the degenerate manifold in the degenerate case. Notice that the spacing between the ladders is given by the detuning, j! j instead of the original W S ladder energy. The correction introduced by the interaction breaks som e of the detuned ladder degeneracies and gives som e substructure to the ladder. Solving the st three factors, $\mathbf{w}_{0}^{N=2} \mathbf{w}_{1}^{N=4} \mathbf{w}_{2}^{N=8} = 0$, to second order, ², we nd that the spectrum is a series of states with energies n 0 , $n^{0} + 2^{2} = {}^{0}$, (n 1) 0 , (n 1) ${}^{0} - 2^{2} = {}^{0}$, etc., with respective degeneracies N =4, N =4, N =8, N =8, etc. No-



 $\begin{array}{c}
1.0 \\
0.8 \\
0.6 \\
0.4 \\
0.2 \\
0.0 \\
2 \\
(b) \\
2 \\
1 \\
2 \\
1 \\
2 \\
3 \\
4 \\
5 \\
6 \\
7 \\
8 \\
Site j
\end{array}$

FIG. 7: (a) D ensity of states, and (b) tunneling probability function D for n = 8 system.

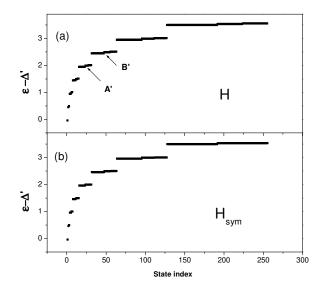


FIG.8: Energy spectra for system with lattice size n = 8. (a) For full H am iltonian H, and (b) for H_{sym} . Here 2 = ! = 1, and = 0.1. A' and B' states are shown in Fig. 9.

tice that here the electron-phonon produces level splittings ², unlike the resonant case where the splitting (bandwidth) is linear in . The problem is also solved num erically and we show the resulting spectra in Fig. 8, for both H (Fig. 8a), and H_{sym} (Fig. 8b). Our analytical results m atch the num erical results for H_{sym} quite well. W e notice again that there are only sm all di erences between the spectra of H and H_{sym} .

FIG.9: (a) Electron probability P (j) for each site j for states A' and B' indicated in Fig.8a. (b) Corresponding phonon distributions N (j).

Figure 9a, shows the electron probability for di erent states in the spectra, labelled A ' and B ' in F ig. 8a. F igure 9b shows the distribution of phonons for the same states. It is apparent that the electron wave function is localized, and separated from its phonon cloud. The two states only di er, basically, on which site to be localized about (as one would expect from their position in di erent 'rungs' in the ladder in Fig. 8a). In fact, the di erent states in ⁰ ladder are associated with di erent lattice sites the (the highest rung states at " ' n ⁰ being localized at j'n). We also show in Fig. 10 the average phonon num ber per state for the entire spectrum. The structure of this gure is quite di erent from that in Fig. 6, as they re ect dram atically di erent dynam ical behavior. A phonon counting argum ent as the electron hops and em its phonons can explain the average number of phonons in the di erent states in Fig. 10, although clearly here it ²). produces a nearly negligible m ixing of states (

One can further explore the extent of the localization nature of the eigenstates. In Fig. 11, we show the electronic probabilities of state (A $^{\prime}$) for various 0 (or electric eld) values. W e m ight expect that the localization length would be 2 = 0, like the localization length for the original W S state is 2t= . This simple expectation is con med by numerical calculations, as seen in Fig. 12, where the solid line shows the $2 = 0^{\circ}$ dependence, and the dots indicate the localization length for states of various ⁰ [the localization length L is extracted from a t to an exponential am plitude drop about its central site, $e^{jx j \in L}$]. One would in fact expect that the manifestation of localization in real space (and energy) would be susceptible to be measured via B loch oscillations, just as in a typical W S ladder. In this case, however, the frequency of B loch oscillations is 0 , and not . Thus

case the dom inant conduction behavior, if any, would be $t \qquad \qquad d$

С

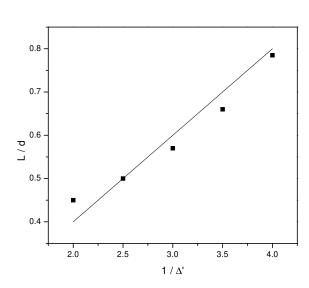


FIG.12: Relation between localization length L and $1 = {}^{0}$. Solid line shows $L=d = 2 = {}^{0}$ dependence, while the dots show value of L obtained from t of functions in Fig.11 to the form exp(jxj=L).

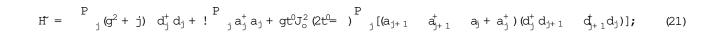
IV. BEYOND SMALL HOPPING AND W EAK COUPLING REGIME

All the discussions so far have been focused on the H am iltonian H (or H $_{\rm sym}$), valid only under the condition of sm all hopping constant t= 1. In this section we extend our discussion beyond this regime, which in principle m ay be relevant, depending on di erent system param eters.

We use the Lang-Firsov canonical transformation $H = e^{S} H_{0} e^{S}$, where $S = g_{j} c_{j}^{\dagger} c_{j} (a_{j} a_{j+1})$, and g = =!. The transform ed H am iltonian takes the form

$$H = X X X
H = "_{j}c_{j}^{+}c_{j} + ! a_{j}^{+}a_{j} g^{2}!c_{j}^{+}c_{j}
+ te^{g^{2}} X [c_{j+1}^{+}c_{j}e^{g(a_{j+1}^{+}a_{j}^{+})}e^{g(a_{j+1}^{-}a_{j}^{+})} + hc:]:$$
(20)

O ne can see that this H am iltonian is suitable for studying strong coupling dynam ics. As in the case of H , we use the operators for W S ladder states, d_j^+ . Then the H am iltonian can be rewritten in the form



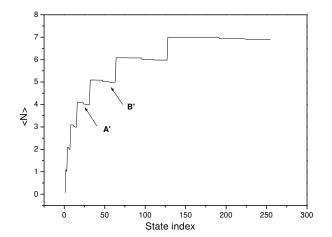


FIG. 10: Totalphonon num ber for each eigenstate in the non- r

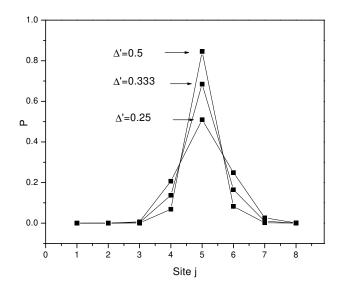


FIG.11: Electron probability P (j) for state A ' in F ig.8a for various detuning values 0 .

the electron-phonon interaction changes the frequency of B loch oscillations, and this e ect m ay be possibly observed in experiment.

From the discussion, it is clear that the eigenstates are localized in the non-resonant regime. As such, they contribute little to transport across the chain. One can easily calculate the quantity D as before. As expected, the value of D is very small (< 10¹²) for every state, and very di erent from the resonant case. This behavior (not shown), is completely consistent with the localized nature of the eigenstates. Thus, we see that in this where $t^0 = te^{g^2}$. We see then that the elective hopping constant t^0 becomes smaller than t. Thus the problem can be mapped to that in the previous section, with elective hopping constant t^0 , and elective coupling constant 0 ,

$$t^{0} = te^{g^{2}}$$
; $^{0} = gt^{0}J_{0}^{2}(2t^{0} =)$: (22)

It is clear that 0 ! 0, when g ! 0, as expected, and the spectrum is the discrete W S ladder in the absence of electron-phonon interaction. M oreover, one can see that for weak coupling, the bandwidth W ' 6 ⁰ is proportional to q, just as in the situation discussed in IIIA (see Fig. 3). Beyond the weak coupling and sm all hopping regime, how ever, W and ⁰ have a nonlinear dependence on g. Figure 13 shows the coupling constant dependence of the bandwidth W for the resonant and stronger coupling lim it, = ! = t = 1. Notice that the bandwidth W ' 1 for & 0:6. At this coupling, the bands in neighboring W S rungs will begin to overlap (and interband term swould need to be considered). It is clear that these corrections to the dependence of W appear also as function of t, , and/or !.

Sim ilar discussions are also relevant in the o -resonant case. For example, since the localization length is proportional to $2^{0}=^{0}$ (section IIIB), there is also a correction to the simple relation L / $2 = ^{0}$, when t and/or g are not sm all. For example, with increasing coupling constant, the correction to the ladder $2^{0^{2}}=^{0}$ m ay become comparable with the spacing between the detuned ladder levels 0 . In that case, the ladder structure for the o -resonance case will also disappear. In this situation, the electron can also become delocalized, even if in the non-resonant regime, but due to the strong coupling .

It is interesting to compare our results to those of Bonca and Trugm an, 7 as one goes from the weak to the strong tunneling regime. These authors found by numerical calculation of the drift velocity that for small electron-phonon coupling, there are energies where the electron cannot propagate. In our approach, this corresponds to the form ation of the quasi-continuous band for each of the W S ladders. The electron cannot propagate when its energy lies in the band gap. However, with increasing coupling constant, the band gap will disappear because of the overlap of subsequent bands. M ore quantitatively, let us consider the case t = ! = 1 (as the param eters in [7]). Since the hopping constant is large, one needs to adopt the form alism in this section. As seen in Fig. 13, the bandwidth increases with increasing coupling constant, producing band overlap for large enough

. This vanishing of the gaps as a function of would coincide with the resum ption of particle drift in the system. Just such behavior was found numerically in [7], and one can now explain it in terms of the level structure of the system. It is also interesting to notice that the overall envelope seen in D is similar to that of the drift velocity: sm all at the center and edge of each band, as shown here in F ig. 7b, and qualitatively like the graphs in gure 4 of reference [7].

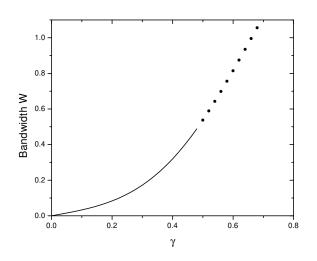


FIG.13: Bandwidth in the resonant and stronger coupling regime as a function of coupling constant . Here, = ! = t = 1. As & 0.6, neighboring bands will overlap, indicated here with dotted line.

V. CONCLUSION

W e have studied the coherent dynam ics of Holstein polarons in a strong electric eld. We have found that with the help of phonons, a sort of quasi-continuous band will form under resonance conditions, even for weak coupling constants. The band shows approximate fractal self-sim ilar structure, which is inherent in the near selfsim ilarity of the Ham iltonian. A lthough the phonons can help the electron jump from one W S ladder state to another, the phonons can also prevent the electron from propagating, if too many phonons are involved. These peculiar interaction di erences give rise to a variety of unusual states, including: (a) delocalized polarons despite the strong electric eld, with a typical phonon cloud accompanying the electron; and (b) states with high degeneracy at the band center, where the electron is localized in a site of the lattice, and the phonon is located away from the electron, in a stretched con guration. The band structure is also manifested in transport properties of the system, which we expect could be observed in tunneling experim ents. The level structure and extension of the di erent states will appear as a modulation of the phonon replicas in the tunneling experiment. For weak coupling, this would only occur if the system is in resonance, ! = , as away from that condition the states are basically localized and would not transport current (except for therm ale ects). In a given structure, the resonance condition can be reached by sweeping the electric

eld, while monitoring the tunneling through the structure. As the spacing between the deform ed rungs and the localization length of the eigenfunction can be adjusted by electric eld, it would be quite interesting to see the transition in experiments. W ith increasing coupling constant, the 'm inibands' will overlap, and give rise to an overallm erging of the phonon replicas in tunneling, even when away from the resonance regime.

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